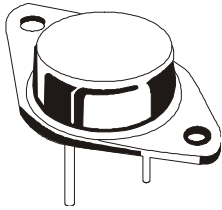


**SILICON PLANAR POWER TRANSISTORS**

**2N3055 NPN**  
**MJ2955 PNP**

**TO-3**  
**Metal Can Package**



**General Purpose Switching and Amplifier Applications**

**ABSOLUTE MAXIMUM RATINGS**

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Base Voltage	$V_{CBO}$	100	V
Collector Emitter Voltage	$V_{CEO}$	60	V
Collector Emitter Voltage ( $R_{BE}=100\Omega$ )	$V_{CER}$	70	V
Emitter Base Voltage	$V_{EBO}$	7	V
Collector Current Continuous	$I_C$	15	A
Base Current	$I_B$	7	A
Power Dissipation @ $T_c=25^\circ\text{C}$	$P_{tot}$	115	W
Derate Above $25^\circ\text{C}$		0.657	W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_j, T_{stg}$	- 65 to +200	$^\circ\text{C}$

**THERMAL RESISTANCE**

Junction to Case	$R_{th(j-c)}$	1.52	$^\circ\text{C/W}$
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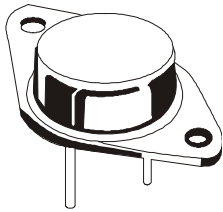
**ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$  unless specified otherwise)**

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Sustaining Voltage	$V_{CEO(sus)}$ *	$I_C=200\text{mA}, I_B=0$	60		V
Collector Emitter Sustaining Voltage	$V_{CER(sus)}$ *	$I_C=200\text{mA}, R_{BE}=100\Omega$	70		V
Collector Cut off Current	$I_{CEX}$	$V_{CE}=100\text{V}, V_{BE}(\text{off})=1.5\text{V}$  $T_c=150^\circ\text{C}$ $V_{CE}=100\text{V}, V_{BE}(\text{off})=1.5\text{V}$		1.0  5.0	mA
Collector Cut off Current	$I_{CEO}$	$V_{CE}=30\text{V}, I_B=0$		0.7	mA
Emitter Cut off Current	$I_{EBO}$	$V_{BE}=7\text{V}, I_C=0$		5.0	mA
Collector Emitter Saturation Voltage	$V_{CE(\text{Sat})}$ *	$I_C=4\text{A}, I_B=400\text{mA}$ $I_C=10\text{A}, I_B=3.3\text{A}$		1.1 3.0	V
Base Emitter on Voltage	$V_{BE(\text{on})}$ *	$I_C=4\text{A}, V_{CE}=4\text{V}$		1.5	V
DC Current Gain	$h_{FE}$ *	$I_C=4\text{A}, V_{CE}=4\text{V}$ $I_C=10\text{A}, V_{CE}=4\text{V}$	20 5	70	

**SILICON PLANAR POWER TRANSISTOR**

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**Metal Can Package**



**ELECTRICAL CHARACTERISTICS (T<sub>c</sub>=25°C unless specified otherwise)**

**Second Breakdown**

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Second Breakdown Collector Current with Base Forward Biased	I <sub>S</sub> /b	V <sub>CE</sub> =40V, t=1.0 s, Nonrepetitive	2.87		A

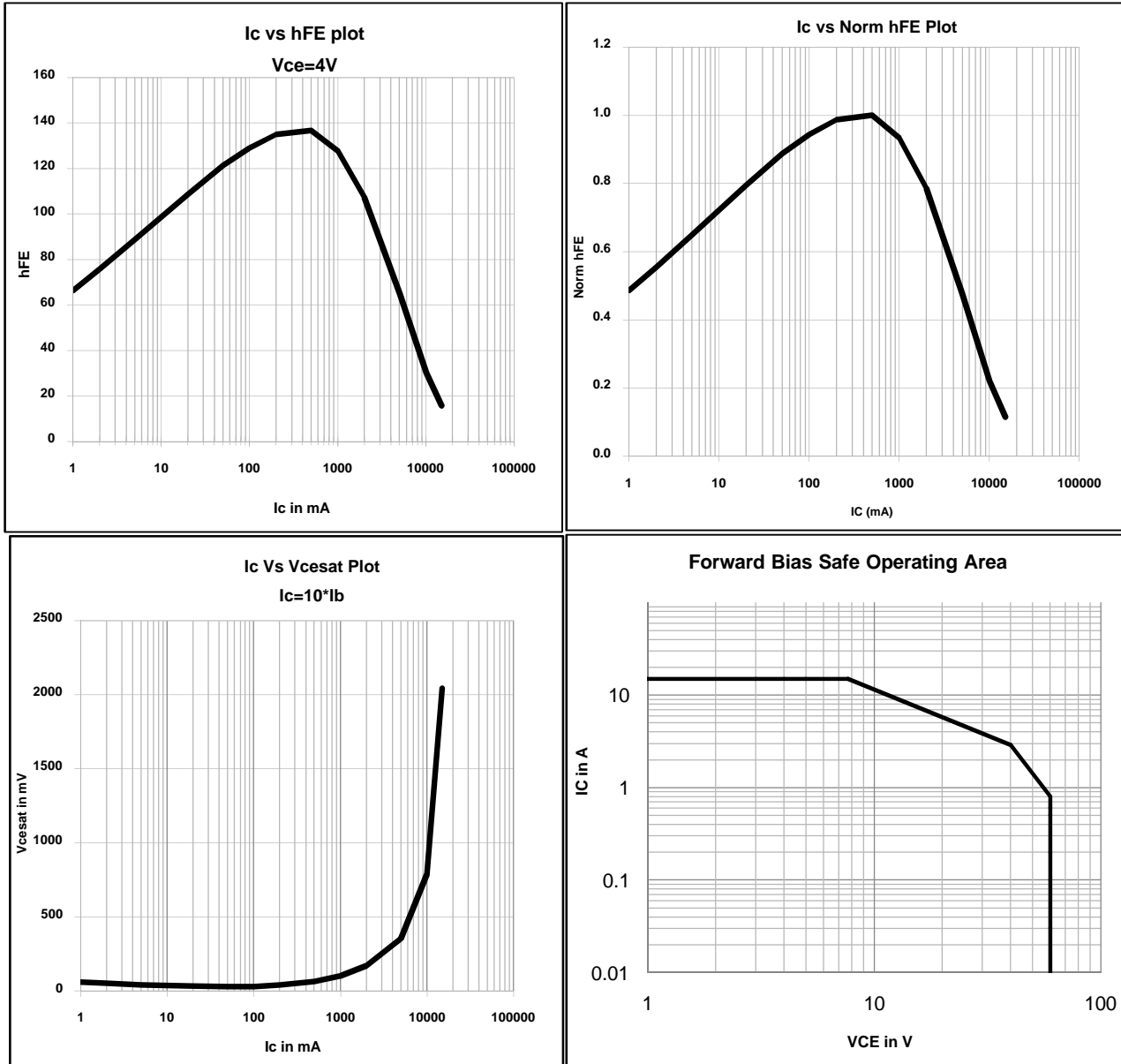
**Dynamic Characteristics**

Current Gain - Bandwidth Product	f <sub>T</sub>	I <sub>C</sub> =0.5A, V <sub>CE</sub> =10V, f=1MHz	2.5		MHz
Small Signal Current Gain	h <sub>fe</sub>	I <sub>C</sub> =1A, V <sub>CE</sub> =4V, f=1KHz	15	120	
Small Signal Current Gain Cutoff Frequency	f <sub>hfe</sub>	I <sub>C</sub> =1A, V <sub>CE</sub> =4V, f=1KHz	10		KHz

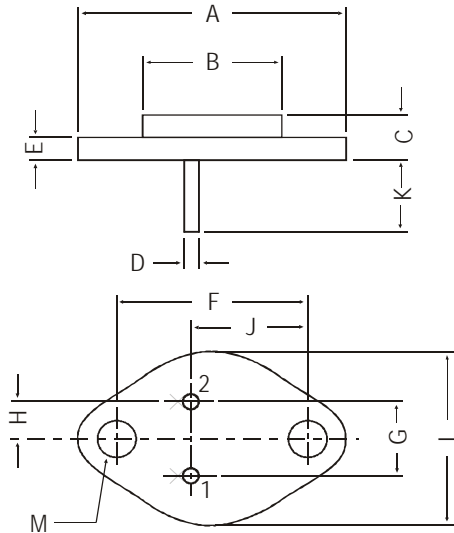
\*Pulse Test: Pulse Width ≤300ms, Duty Cycle ≤2%



### CHARACTERISTICS PLOTS

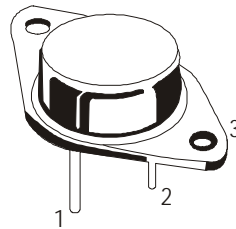


### TO-3 Metal Can Package



All dimensions in mm.

DIM	MIN.	MAX.
A	—	39.37
B	—	22.22
C	6.35	8.50
D	0.96	1.09
E	—	1.77
F	29.90	30.40
G	10.69	11.18
H	5.20	5.72
J	16.64	17.15
K	11.15	12.25
L	—	26.67
M	3.84	4.19



#### PIN CONFIGURATION

1. BASE
2. EMITTER
3. COLLECTOR

### Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-3	100 pcs/pkt	1.3 kg/100 pcs	12.5" x 8" x 1.8"	0.1K	17" x 11.5" x 21"	2K	27.5 kgs



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## Notes

### Disclaimer

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